

Numerical simulation of three-dimensional grain growth in materials containing finely dispersed second-phase particles with the phase field method

Liesbeth Vanherpe¹ Nele Moelans² Bart Blanpain²
Stefan Vandewalle¹

¹Department of Computer Science, K.U.Leuven

²Department of Metallurgy and Materials Engineering, K.U.Leuven

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Outline

Grain growth

Polycrystalline materials

Grain growth in presence of second-phase particles

Phase field model and simulation

Phase field model

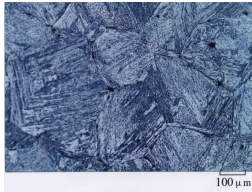
Simulation

Bounding box algorithm

Application

Conclusion

Polycrystalline materials

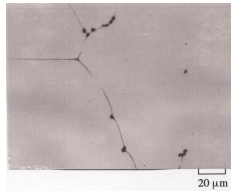
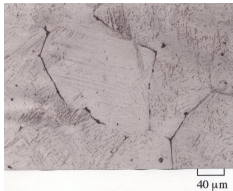


[M. Guo]

- ▶ microstructure of grains with different crystallographic orientations
- ▶ material properties depend on microstructure
- ▶ study of grain growth: increase of mean grain size



Grain growth in presence of second-phase particles

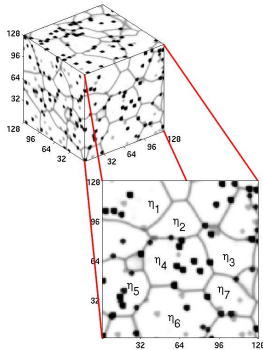


[M. Guo]

- ▶ control grain size by addition of impurities
- ▶ applications
 - ▶ design of high-strength steels for construction applications
 - ▶ design of thin metallic films in microelectronic devices
- ▶ importance of computational research



Phase field model



- ▶ set of phase field variables

$$\eta_i(\mathbf{r}, t), \quad i = 1, \dots, p$$

- ▶ inside grain i

$$(\eta_1, \dots, \eta_i, \dots, \eta_p) = (0, \dots, \pm 1, \dots, 0)$$

- ▶ parameter ϕ for the second-phase particles

- ▶ $\phi = 1$ inside particles
- ▶ $\phi = 0$ else

Phase field model

- ▶ kinetic equations

$$\frac{\partial \eta_i}{\partial t} = -L \frac{\partial F}{\partial \eta_i}, \quad i = 1, \dots, p$$

- ▶ free energy

$$F = \int_V \left(\sum_{i=1}^p \left(\frac{\eta_i^4}{4} - \frac{\eta_i^2}{2} \right) + \sum_{i=1}^p \sum_{j \neq i}^p \eta_i^2 \eta_j^2 + \phi^2 \sum_{i=1}^p \eta_i^2 + \sum_{i=1}^p \frac{\kappa}{2} (\nabla \eta_i)^2 \right) dV$$

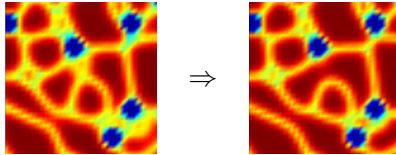
- ▶ set reaction-diffusion partial differential equations

$$\frac{\partial \eta_i}{\partial t} = L \kappa \nabla^2 \eta_i - L (\eta_i^3 - \eta_i + 2\eta_i \sum_{j \neq i}^p \eta_j^2 + 2\eta_i \phi^2), \quad i = 1, \dots, p$$



Points of attention

- ▶ prevent grain coalescence:



solution large amount of phase field variables

- ▶ grains, boundaries and particles

solution fine resolution of grid

- ▶ statistically relevant results

solution large amount of grains

Parallel computing

$$\frac{\eta_i^{n+1} - \eta_i^n}{\partial t} = L\kappa \nabla^2 \eta_i^{n+1} - L \left(\eta_i^3 - \eta_i + 2\eta_i \left(\sum_{j \neq i}^p \eta_j^2 + \phi^2 \right) \right)^n, \quad i = 1, \dots, p$$

- ▶ semi-implicit discretisation
 - + p smaller systems to solve
 - + allows for large time step
- ▶ parallel computing
 - + assign equations to different processors
 - + compute solutions in parallel
 - communication step: large message



Characteristics of the solutions

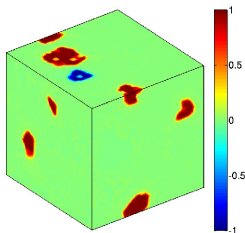
Definition

A phase field variable η_i is active at a grid point \mathbf{r} when $|\eta_i(\mathbf{r})| > \epsilon$, with ϵ a small positive threshold value.

Observations:

1. at each grid point, only a few η_i active
2. values of η_i only evolve at the grain boundaries

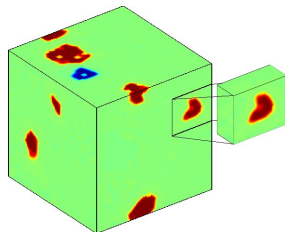
⇒ solve only locally



Bounding box algorithm

Preprocessing step

1. apply threshold ϵ
2. locate grains: connected grid points \mathbf{r} where $|\eta_i(\mathbf{r})| > \epsilon$
3. determine bounding boxes
 - ▶ bounding box: smallest cuboid containing grain
 - ▶ grain numbering procedure to prevent coalescence



Computation step

Bounding box algorithm

Preprocessing step

Computation step

- ▶ solve the equations only locally:

$$\frac{\eta_i^{n+1} - \eta_i^n}{\partial t} = L\kappa \nabla^2 \eta_i^{n+1} - L \left(\eta_i^3 - \eta_i + 2\eta_i \left(\sum_{j \neq i}^p \eta_j^2 + \phi^2 \right) \right)^n$$

for time steps $t = 1, \dots, n$

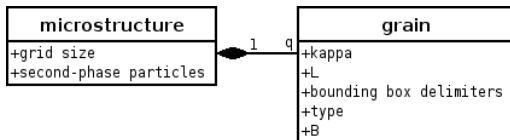
1. for all grid points: compute $\sum \eta_j^2 + \phi^2$
2. for all bounding boxes: solve equations

- ▶ only values inside boxes are kept in memory



Bounding box algorithm

Data structure



- ▶ object-oriented data structure
- ▶ advantages in post-processing
 - ▶ location of grains known
- ▶ extensible to more complex models
 - ▶ anisotropy
 - ▶ evolving second-phase particles

Computational requirements

Table 1: Number of phase field values per grid point on a $256 \times 256 \times 256$ grid with $p = 100$.

simulation time t	threshold value ϵ				conventional
	10^{-3}	10^{-4}	10^{-5}	10^{-6}	
t_s	5.75	6.48	7.26	8.10	100
$t_s + 200$	6.71	6.74	6.90	6.90	100
$t_s + 400$	6.72	6.73	6.81	6.81	100
$t_s + 600$	6.68	6.69	6.73	6.73	100
$t_s + 800$	6.64	6.65	6.68	6.68	100

- ▶ approx. 7 instead of p phase field values per grid point
- ▶ scales with system size, not with p



Computational requirements

Table 2: Requirements of 5000 time steps with $\epsilon = 10^{-5}$ on a $256 \times 256 \times 256$ grid with $p = 100$.

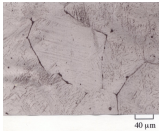
simulation time	b. box (on 1 proc)		conv. (on 20 procs)	
	time (h)	mem (GB)	time (h)	mem (GB)
200 → 400	6.3	2.8	6.8	30.3
400 → 600	4.7	2.2	6.8	30.3
600 → 800	3.8	1.9	6.8	30.3
800 → 1200	3.5	1.7	6.8	30.3
1200 → 1400	3.1	1.6	6.8	30.3

- ▶ 1 instead of 20 processors and faster
- ▶ efficiency increases for coarser topology

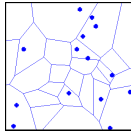


Initial microstructure

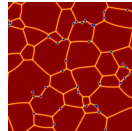
- ▶ start from initial polycrystalline microstructure



microscopic images

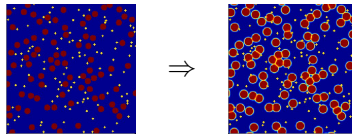


Voronoi calculation



phase field simulation

- ▶ generate nuclei according to some distribution



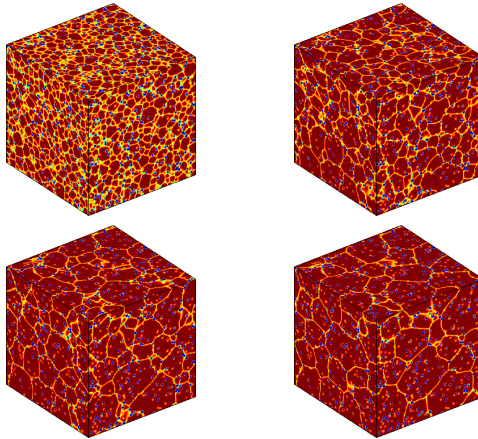
Application

Grain growth in presence of second-phase particles

- ▶ initial polycrystalline microstructure obtained by ‘conventional’ phase field simulation
 - ▶ $256 \times 256 \times 256$ grid
 - ▶ 100 phase field variables
 - ▶ $f_V = 5\%$, 8% and 12% of particles, radius $r = 3$
 - ▶ performed on 20 processors
- ▶ bounding box algorithm
 - ▶ threshold $\epsilon = 10^{-5}$
 - ▶ only 1 processor
 - ▶ approx. three times faster

Application

Microstructural evolution



Application Results

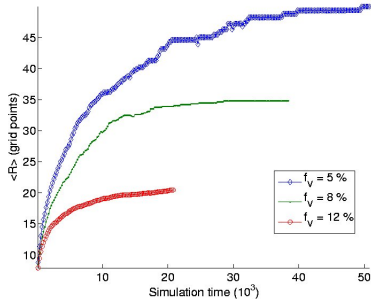


Fig 1: Evolution of mean grain size for different f_V .

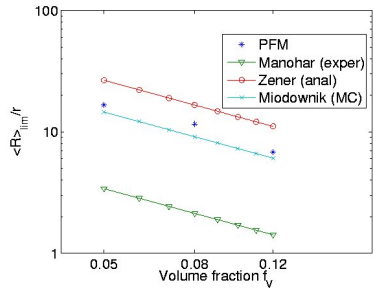


Fig 2: Comparison with other results.



Conclusion

- ▶ phase field model for grain growth in presence of second-phase particles
 - ▶ computationally intensive
- ▶ three-dimensional simulation
 - ▶ parallel computing
 - ▶ semi-implicit discretisation
 - ▶ larger systems, but large communication message
 - ▶ bounding box algorithm
 - ▶ less computing time, less memory
 - ▶ no grain coalescence
- ▶ application

Thank you

Thank you! Questions?